



PHOTODIODE

Si photodiode

S9674



Suitable for lead-free solder reflow, operating/storage temperature: -40 to +125 °C

S9674 is a highly reliable photodiode designed for in-vehicle applications and is compatible with lead-free solder reflow processes. The newly developed small, thin leadless package allows reducing the mount area on a printed circuit board.

Features

- Suitable for lead-free solder reflow (Reflow peak temperature: 260 °C, JEDEC LEVEL 5a)
- Surface mount type, small and thin leadless package
- High reliability for automotive applications
Operating/storage temperature: -40 to +125 °C
- Active area: 2 × 2 mm
- High sensitivity: 0.7 A/W ($\lambda=960$ nm)

Applications

- Automotive devices
(For rain sensor and sun sensor, etc.)

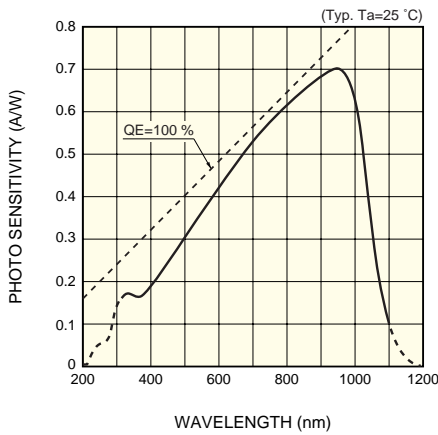
■ Absolute maximum ratings

Parameter	Symbol	Value	Unit
Reverse voltage	VR Max.	10	V
Operating temperature	Topr	-40 to +125	°C
Storage temperature	Tstg	-40 to +125	°C

■ Electrical and optical characteristics (Ta=25 °C)

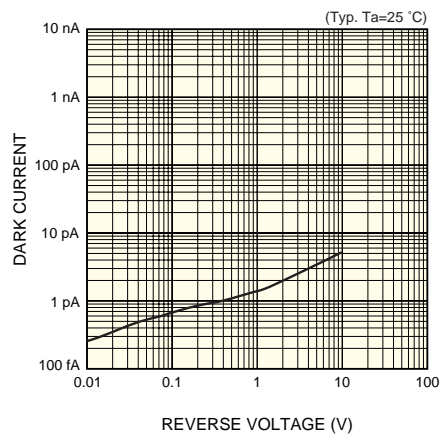
Parameter	Symbol	Condition	Min.	Typ.	Max.	Unit
Spectral response range	λ		-	320 to 1100	-	nm
Peak sensitivity wavelength	λ_p		-	960	-	nm
Photo sensitivity	S	$\lambda=\lambda_p$	0.6	0.7	-	A/W
Short circuit current	Isc	100 lx, 2856 K	-	4.8	-	μ A
Temperature coefficient of Isc	-		-	+0.1	-	%/°C
Half-value angle	-		-	± 60	-	degree
Dark current	ID	VR=5 V	-	0.005	1	nA
Temperature coefficient of ID	TCID		-	1.12	-	times/°C
Rise time	tr	VR=0 V, RL=1 k Ω 10 to 90 %	-	2	-	μ s
Terminal capacitance	Ct	VR=0 V, f=10 kHz	-	450	-	pF

■ Spectral response



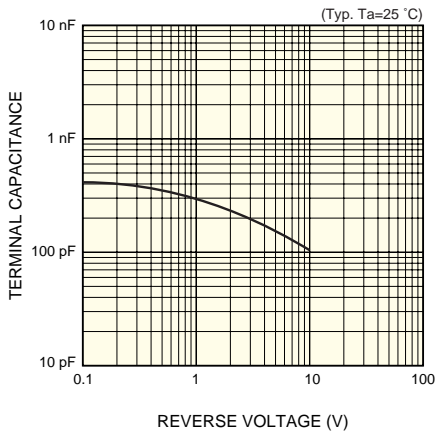
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■ Dark current vs. reverse voltage



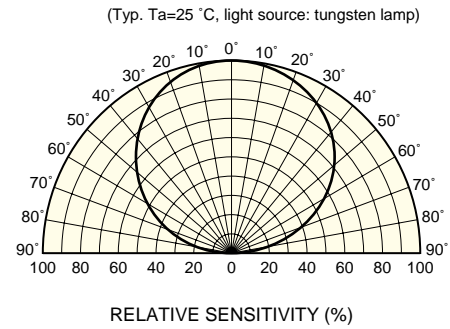
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■ Terminal capacitance vs. reverse voltage



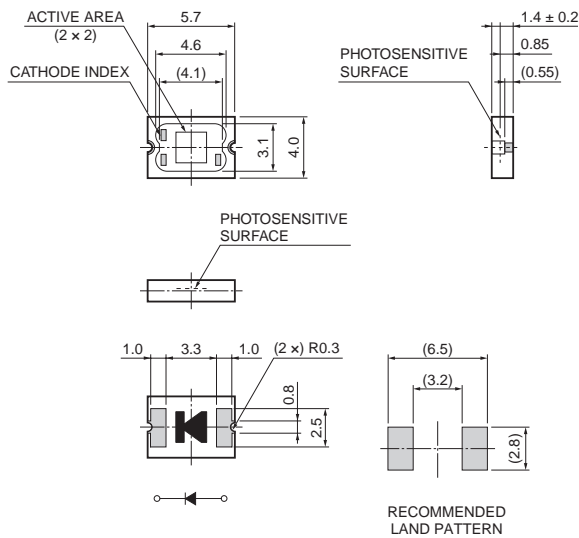
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■ Directivity



KSPDB0249EA

■ Dimensional outline (unit: mm)



KSPDA0179EA

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